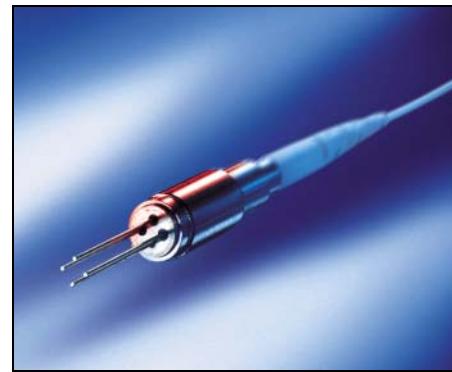
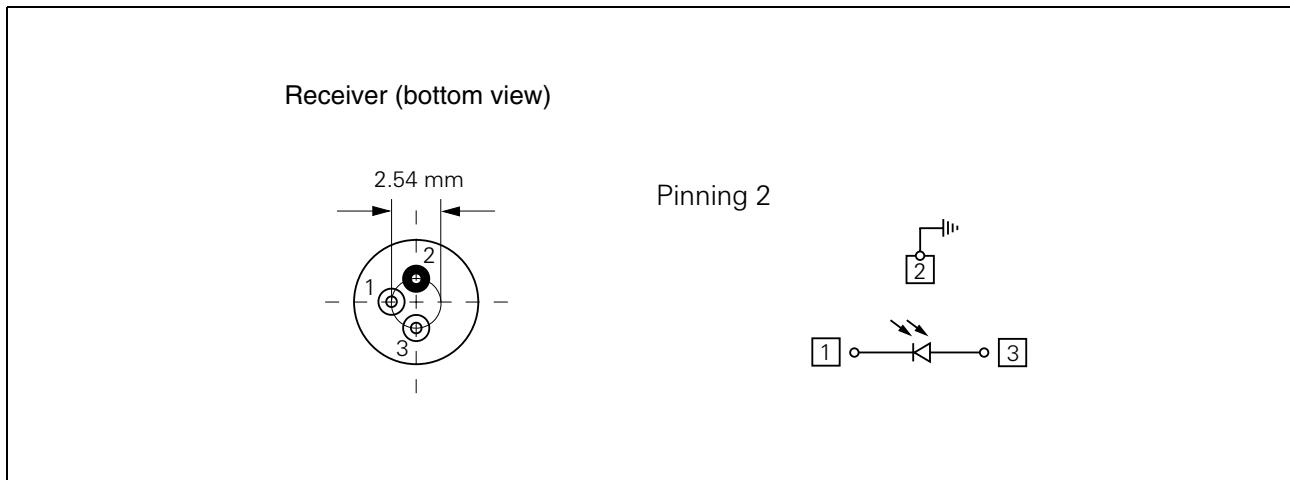


Ternary PIN Photodiode**SRD00224x**
SRD00225x**Features**

- InGaAs/InP PIN photodiode
- Designed for applications in fiber-optics communication systems
- Sensitive receiver for 2nd and 3rd optical window (1300 nm and 1550 nm)
- Suitable for bit rates up to 2.5 Gbit/s
- For singlemode and multimode applications SONET OC-1...OC-48, SDH STM-1...STM-16
- Low junction and low package capacitance
- Fast switching times
- Low dark current
- Excellent noise immunity
- High reverse current stability from planar structure
- Hermetically sealed TO46 package



Pin Configuration**Pin Configuration****Figure 1 Receiver**

Description

The Infineon optical receiver module has been designed for use in optical networks and is suitable for bit rates up to max. 2.5 Gbit/s if used without any TIA.

The optical receiver module uses a high-speed PIN photodetector optional coupled with a hybrid low noise transimpedance amplifier (PIN-TIA). The optical receiver photodiode can be used for 1310 nm or 1550 nm optical communications.

The PIN photodiode is made of InGaAs/InP and has an active diameter of 75 μm . The function of the PIN and PIN-TIA optical receiver module is to detect input optical power, to transduce the incident radiation into current (PIN) and then to convert the current into a voltage (PIN-TIA).

The low input noise current density of the used transimpedance amplifiers in PIN-TIA's provides the optical receiver module, when used with appropriate filtering, with ample sensitivity for realizing minimum input power requirements. Designers of optical receivers can use the module in any application that benefits from integration of the photodiode and TIA into a TO coaxial package. Typical for such applications are receivers for digital crossconnects, digital loop carriers, add/drop-multiplexers and optical network units.

Last but not least the fast switching times, low dark currents and the packaging in a compact and hermetically sealed TO46 make the optical receivers usable in many other fiber optic receiver applications. One application is the use in a Compact realization of a transceiver in one module like the so called BIDI® ([Figure 2](#)).

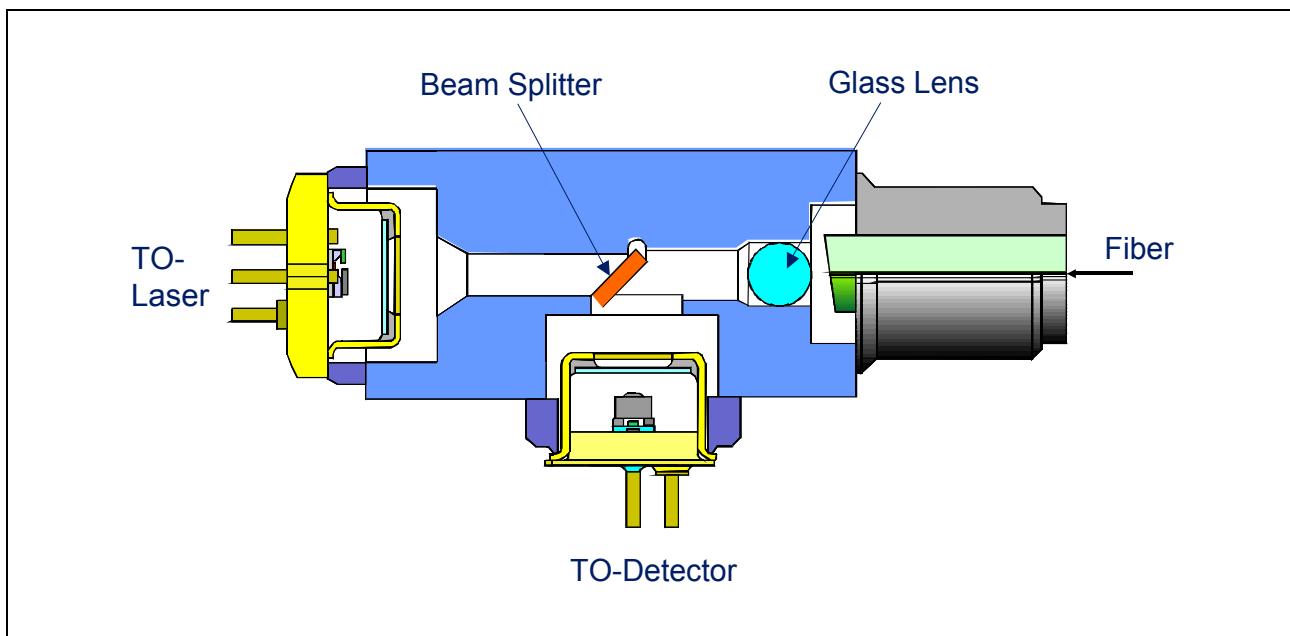


Figure 2 Compact Realization of the Transceiver in One Module

Technical Data

All data refer to the full operating temperature range unless otherwise specified.

Absolute Maximum Ratings

| Parameter | Symbol | Limit Values | | Unit |
|--|------------|--------------|------|------|
| | | min. | max. | |
| Module | | | | |
| Operating temperature range at case | T_C | -40 | 85 | °C |
| Storage temperature range | T_{stg} | -40 | 85 | °C |
| Soldering temperature ($t_{max} = 10$ s, 2 mm distance from bottom edge of case) | T_S | | 260 | °C |
| Receiver Diode | | | | |
| Reverse Voltage | V_R | | 20 | V |
| Forward Current | I_F | | 10 | mA |
| Optical power into the optical port | P_{port} | | 1 | mW |

Receiver Diode Electro-Optical Characteristics

| Parameter | Symbol | Limit Values | | | Unit |
|---|--|--------------|------|---------|------|
| | | min. | typ. | max. | |
| Spectral sensitivity $V_R = -2$ V, $P_{opt} = 1$ μ W | S_{1310nm} S_{1550nm} | 0.8 | 0.9 | | A/W |
| Change in Spectral Sensitivity in Operating Temperature Range | ΔS | | | 0.2 | %/K |
| Dark current $V_R = 5$ V, $P_{opt} = 0$ mW | $I_{D 25^\circ C}$ $I_{D 85^\circ C}$ | | | 5 50 | nA |
| Total Capacitance $V_R = 3$ V, $f = 1$ MHz, $V_{RF} = 30$ mV | C | | 0.8 | 1 | pF |
| Rise and fall time (10%...90%) $V_R = 5$ V, $P_{opt} = (0.1...1)$ mW, 50Ω | t_r, t_f | | 200 | 300 | ps |
| Cut Off Frequency $\lambda = 1310$ nm, $V_R = 5$ V, 50Ω | f_{3dB} | 1 | | | GHz |
| Return Loss $\lambda = 1310$ nm | RL | | | -27 | dB |

End of Life Time Characteristics

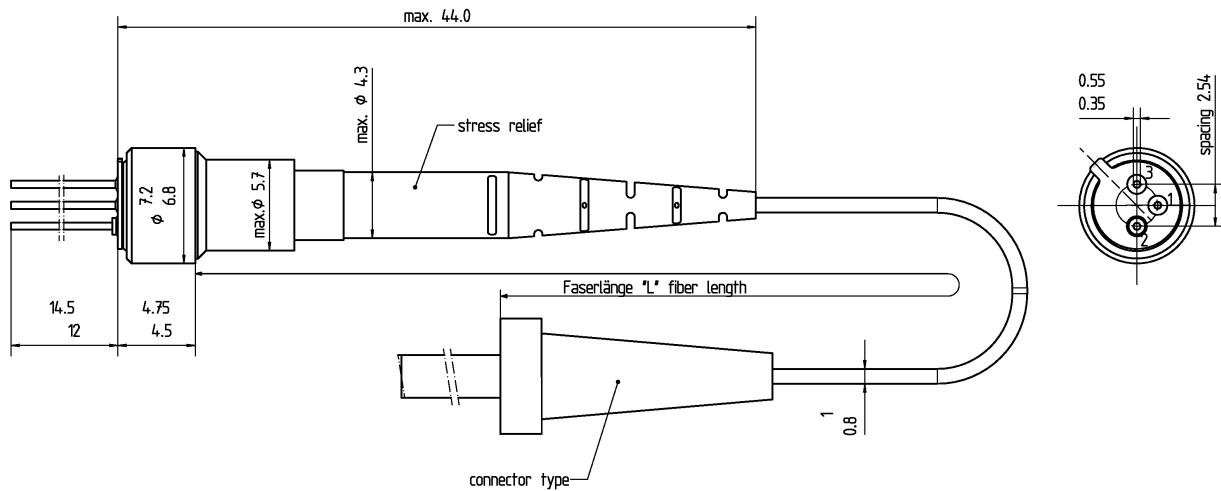
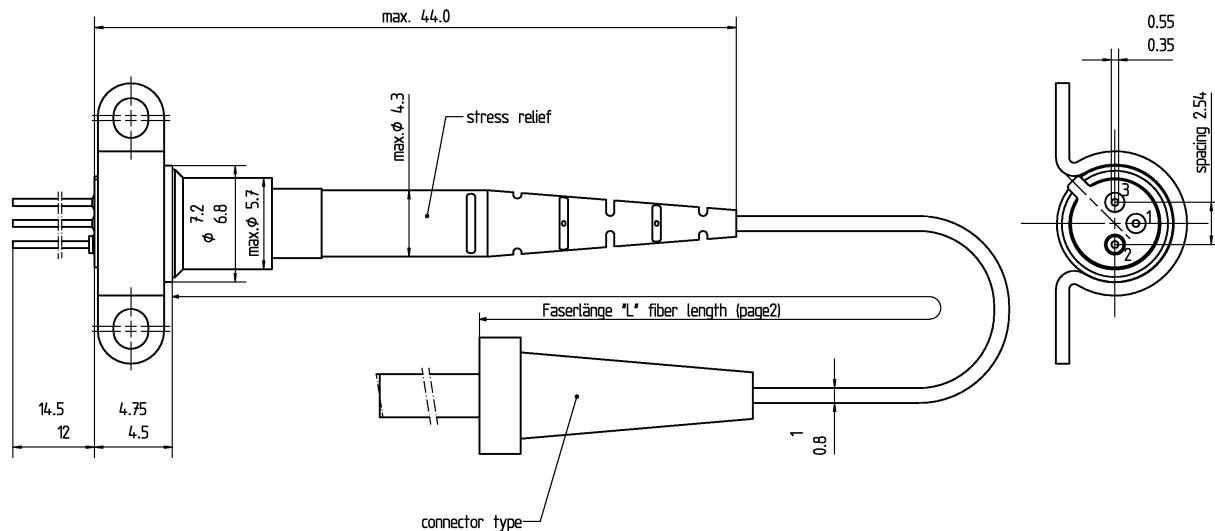
| Parameter | Symbol | Limit Values | | Unit |
|---|--------|--------------|------|------|
| | | min. | max. | |
| Detector Dark Current, $V_R = 2$ V, $T = T_{max}$ | I_R | | 400 | nA |

Fiber Data

The mechanical fiber characteristics are described in the following table.

Fiber Characteristics

| Parameter | Limit Values | | | Unit |
|---|--------------|------|------|------|
| | min. | typ. | max. | |
| Mode Field Diameter | | 50 | | µm |
| Cladding Diameter | 123 | 125 | 127 | |
| Mode Field/Cladding Concentricity Error | | | 1 | |
| Cladding Non-circularity | | | 2 | % |
| Mode Field Non-circularity | | | 6 | |
| Cut off Wavelength | 1270 | | | nm |
| Jacket Diameter | 0.8 | | 1 | mm |
| Bending Radius | 30 | | | |
| Tensile Strength Fiber Case | 5 | | | N |
| Length | 0.8 | | 1.2 | m |

Package Outlines
Package Outlines
SRD00224x

SRD00225x


Dimensions in mm

Figure 3

Flange Options

| Type | Flange |
|-----------|---------|
| SRD00224x | without |
| SRD00225x | with |

Connector Options

| Model | Type |
|-----------------------------|----------------------|
| SRD00224H | MM FC/PC |
| SRD00225H | |
| SRD00224G | SM FC/PC |
| SRD00225G | |
| SRD00224O | MM SC/PC 0° |
| SRD00225O | |
| SRD00224N | SM SC/PC 0° |
| SRD00225N | |
| SRD00224Q | MM SC 8° APC |
| SRD00225Q | |
| SRD00224P | SM SC 8° APC |
| SRD00225P | |
| SRD00224W | MM without connector |
| SRD00225W | |
| SRD00224Z | SM without connector |
| SRD00225Z | |
| Other connectors on request | |

SRD00224x

SRD00225x

Revision History: **2001-12-01**

DS0

Previous Version:

| Page | Subjects (major changes since last revision) |
|-------------|---|
| | Document's layout has been changed: 2002-Aug. |

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